www.vishay.com

# Hyperfast Rectifier, 12 A FRED Pt<sup>®</sup>



D-PAK (TO-252AA)

PRIMARY CHARACTERISTICS								
I <sub>F(AV)</sub>	12 A							
V <sub>R</sub>	600 V							
V <sub>F</sub> at I <sub>F</sub>	1.34 V							
t <sub>rr</sub> (typ.)	18 ns							
T <sub>J</sub> max.	175 °C							
Package	DPAK (TO-252AA)							
Circuit configuration	Single							

#### FEATURES

- Hyperfast recovery time, reduced Q<sub>rr</sub> and soft recovery
- 175 °C maximum operating junction temperature
- For PFC CRM/CCM operation
- Low forward voltage drop
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### **DESCRIPTION / APPLICATIONS**

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS inverters or as freewheeling diodes. Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS										
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS						
Peak repetitive reverse voltage	V <sub>RRM</sub>		600	V						
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 132 °C	12							
Non-repetitive peak surge current	I <sub>FSM</sub>	T <sub>J</sub> = 25 °C	110	А						
Peak repetitive forward current	I <sub>FM</sub>	$T_{C} = 132 \ ^{\circ}C, f = 20 \ kHz, d = 50 \ \%$	24							
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-65 to +175	°C						

<b>ELECTRICAL SPECIFICATIONS</b> ( $T_J$ = 25 °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	Ι <sub>R</sub> = 100 μΑ	600	-	-				
Forward voltage	VF	I <sub>F</sub> = 12 A	-	1.73	2.5	V			
	۷F	I <sub>F</sub> = 12 A, T <sub>J</sub> = 125 °C	-	1.34	1.8				
Reverse leakage current	I <sub>R</sub>	V <sub>R</sub> = V <sub>R</sub> rated	-	-	10				
		$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$		-	100	μA			
Junction capacitance	CT	V <sub>R</sub> = 600 V	-	8	-	pF			
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	8	-	nH			

 Revision: 11-Apr-18
 1
 Document Number: 93254

 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com
 DiodesEurope@vishay.com

 THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFI
 Downloaded From Oneyac.com

 W.vishay.com/doc?91000
 W.vishay.com/doc?91000





HALOGEN

FREE



<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J$ = 25 °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS		
Reverse recovery time		$I_F = 1 \text{ A}, dI_F/dt = 10$	00 A/µs, V <sub>R</sub> = 30 V	-	18	22			
	+	$I_F = 1 \text{ A}, dI_F/dt = 50$	-	22	-	ns			
	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	26	-	A		
		T <sub>J</sub> = 125 °C		-	47	-			
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C	l <sub>F</sub> = 12 A dI <sub>F</sub> /dt = 200 A/µs	-	3.5	-			
Peak recovery current		T <sub>J</sub> = 125 °C	$V_{\rm R} = 390 \text{ V}$	-	5.4	-			
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	48	-			
		T <sub>J</sub> = 125 °C		-	137	-	nC		

THERMAL - MECHANICAL SPECIFICATIONS										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-65	-	175	°C				
Thermal resistance, junction to case per leg	R <sub>thJC</sub>		-	1.3	1.7	°C/W				
Approximate weight				0.3		g				
Approximate weight				0.01		oz.				
Marking device		Case style DPAK (TO-252AA)	12EWH06FN							

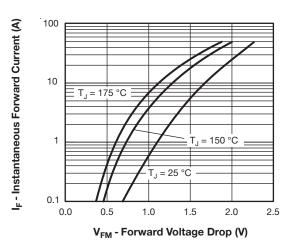


Fig. 1 - Typical Forward Voltage Drop Characteristics

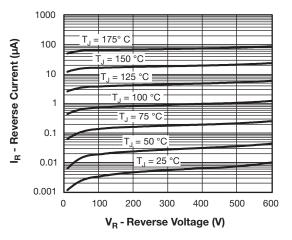


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



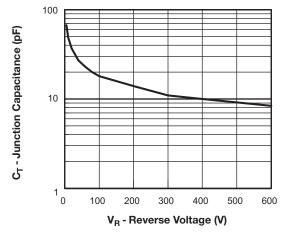


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

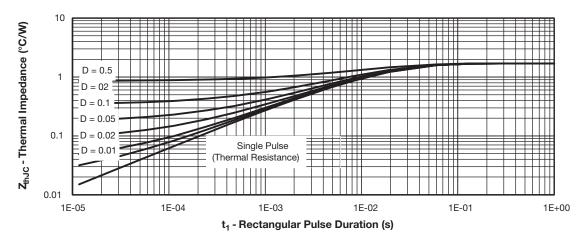
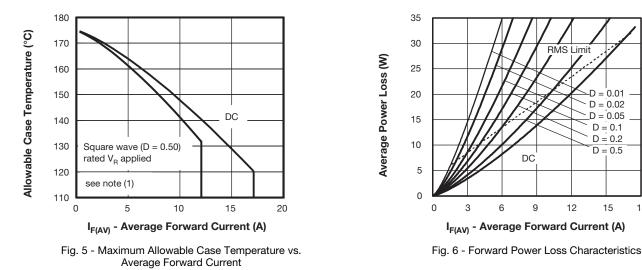


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics



Revision: 11-Apr-18

3

Document Number: 93254

-D 0.01 D = 0.02 D = 0.05

12

D = 0.1 D = 0.2

D = 0.5

15

18

For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFI Downloaded From Oneyac.com

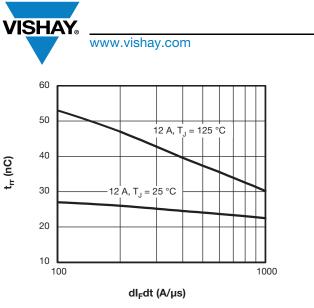


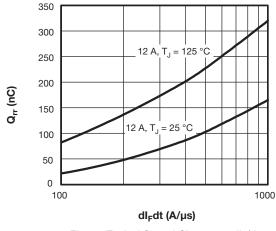
Fig. 7 - Typical Reverse Recovery Time vs.  $dI_F/dt$ 

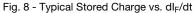
Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \\ \end{array}$ 







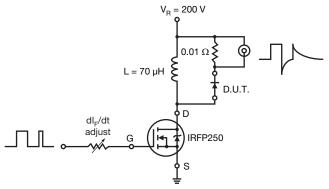


Fig. 9 - Reverse Recovery Parameter Test Circuit

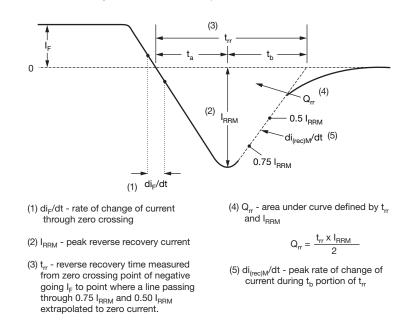


Fig. 10 - Reverse Recovery Waveform and Definitions

Revision: 11-Apr-18	4	Document Number: 93254
For technical questions within your region: D	iodesAmericas@vishay.com, Diodes/	<u>Asia@vishay.com, DiodesEurope@vishay.com</u>
		DESCRIBED HEREIN AND THIS DOCUMENT
ARE SUBJECT TO SPECIF	Downloaded From Oneyac.com	w.vishay.com/doc?91000

### **ORDERING INFORMATION TABLE**

Device code	VS-	12	Е	w	н	06	FN	TRL	-M3		
	1	2	3	4	5	6	7	8	9		
	1 - Vishay Semiconductors product										
	2 -	2 - Current rating (12 = 12 A)									
	3 -	3 - Circuit configuration:									
		E = single diode									
	4 -	- Pac	Package identifier:								
		W =	D-PAK								
	5 -	- H = hyperfast recovery									
	6 -	- Volt	tage rati	ng (06 =	= 600 V)						
	7 -	- FN	= TO-25	52AA							
	8 -	• N	one = tu	be							
		• TR = tape and reel									
		• TI	<ul> <li>TRL = tape and reel (left oriented)</li> </ul>								
		• TI	RR = tap	be and r	eel (righ	it orient	ed)				
	9 -		, ironmer								
				-							

-M3 = halogen-free, RoHS-compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-12EWH06FN-M3	75	3000	Antistatic plastic tube						
VS-12EWH06FNTR-M3	2000	2000	13" diameter reel						
VS-12EWH06FNTRL-M3	3000	3000	13" diameter reel						
VS-12EWH06FNTRR-M3	3000	3000	13" diameter reel						

LINKS TO RELATED DOCUMENTS							
Dimensions	www.vishay.com/doc?95627						
Part marking information	www.vishay.com/doc?95176						
Packaging information	www.vishay.com/doc?95033						
SPICE model	www.vishay.com/doc?95220						

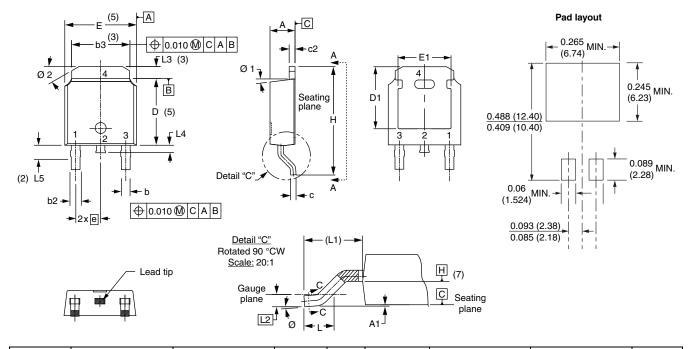






D-PAK (TO-252AA) "M"

#### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIM	MILLIMETERS		INCHES		s symbo	SAMBOI	MILLIN	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES		STWDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	2.18	2.39	0.086	0.094			е	2.29	BSC	0.090	BSC	
A1	-	0.13	-	0.005			Н	9.40	10.41	0.370	0.410	
b	0.64	0.89	0.025	0.035			L	1.40	1.78	0.055	0.070	
b2	0.76	1.14	0.030	0.045			L1	2.74	BSC	0.108	REF.	
b3	4.95	5.46	0.195	0.215	3		L2	0.51	BSC	0.020	BSC	
С	0.46	0.61	0.018	0.024			L3	0.89	1.27	0.035	0.050	3
c2	0.46	0.89	0.018	0.035			L4	-	1.02	-	0.040	
D	5.97	6.22	0.235	0.245	5		L5	1.14	1.52	0.045	0.060	2
D1	5.21	-	0.205	-	3		Ø	0°	10°	0°	10°	
E	6.35	6.73	0.250	0.265	5		Ø1	0°	15°	0°	15°	
E1	4.32	-	0.170	-	3		Ø2	25°	35°	25°	35°	

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994

<sup>(2)</sup> Lead dimension uncontrolled in L5

<sup>(3)</sup> Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad

(4) Section C - C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip

(5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

<sup>(6)</sup> Dimension b1 and c1 applied to base metal only

<sup>(7)</sup> Datum A and B to be determined at datum plane H

<sup>(8)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-252AA

Document Number: 95627



Vishay

## Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

单击下面可查看定价,库存,交付和生命周期等信息

>>Vishay(威世)